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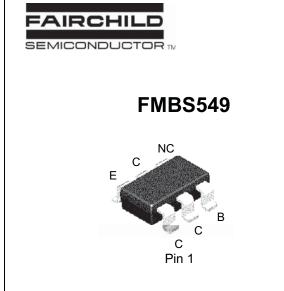
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Fairchild Semiconductor FMBS549

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Package: SuperSOT-6 single Mark : .S1

PNP Low Saturation Transistor

This device is designed with high current gain and low saturation voltage with collector currents up to 2A continous. Sourced from process PB.

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	30	V
V _{СВО}	Collector-Base Voltage	35	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current- Continuous - Peak Pulse Current	1 2	A A
TJ, TSTG	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristics	Мах	Units
PD	Total Device Dissipation*	700	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, total	180	°C/W
	*		

*Device mounted on a 1 in2 pad of 2 oz copper.

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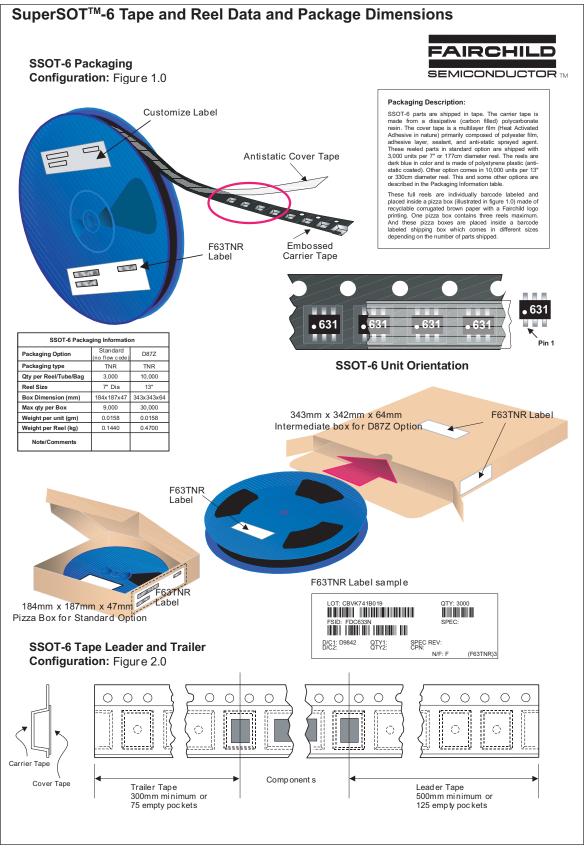


Symbol	Electrical Characteristics TA = 25°C unless otherwise noted							
	Parameter	Test Conditions	Min	Мах	Units			
OFF CHAF	RACTERISTICS							
BV _{CEO}	Collector to Emitter Voltage	Ic = 10 mA	30		V			
BV _{CBO}	Collector to Base Voltage	Ic = 100 uA	35		V			
BV _{EBO}	Emitter to Base Voltage	le = 100 uA	5		V			
I _{СВО}	Collector Cutoff Current	Vcb = 30 V Vcb = 30 V, Ta= 100C		100 10	nA uA			
I _{EBO}	Emitter Cutoff Current	Veb = 4 V		100	nA			
	ACTERISTICS							
hfe	DC Current Gain	$\begin{array}{llllllllllllllllllllllllllllllllllll$	70 100 80 40 100	300	-			
V _{CE(sat)}	Collector-Emitter Saturation Voltage			200 350 500 750	mV mV mV mV			
V _{BE(sat)}	Base-Emitter Saturation Voltage	Ic = 1 A, Ib = 100 mA		1.25	V			
V _{BE(on)}	Base-Emitter On Voltage	Ic = 1 A, Vce = 2 V		1	V			
SMALL SI	GNAL CHARACTERISTICS							
C _{obo}	Output Capacitance	Vcb = 10V, f = 1MHz	25		pF			
f _T	Current Gain - Bandwidth Product	Vce = 5 V, Ic = 100mA, f = 100MHz	100		MHz			

fmbs549.lwp Rev A PrPB

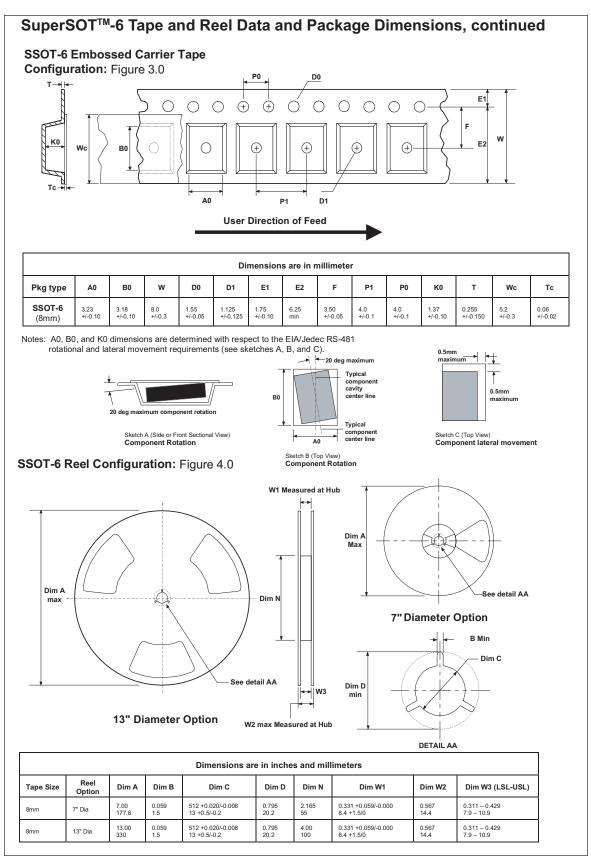
FMBS549





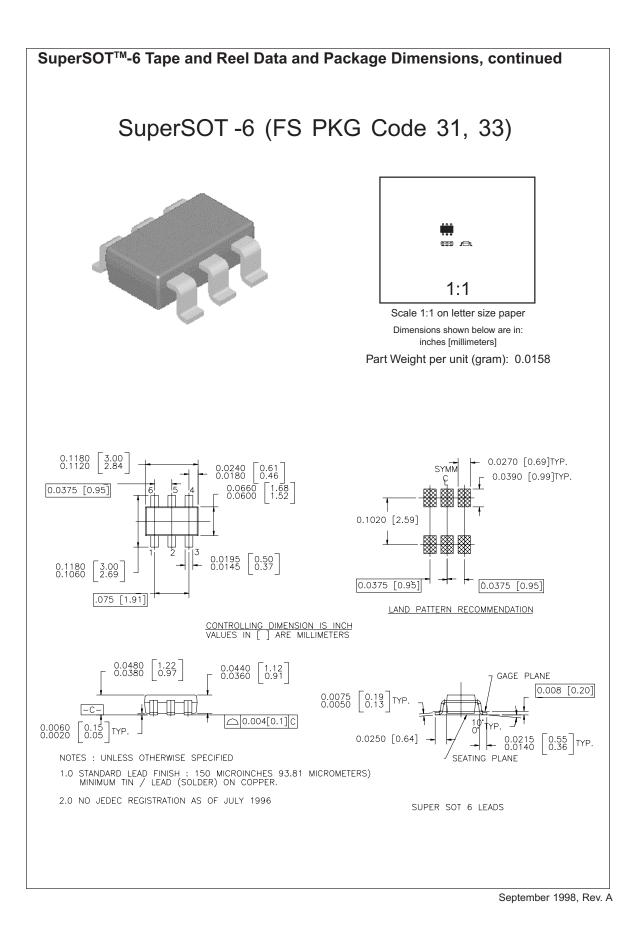
August 1999, Rev. C





July 1999, Rev. C







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